



### NE85633-T1B-R23-A Information

Part Number NE85633-T1B-R23-A

Manufacturer CEL

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF

**Description RF TRANSISTOR NPN SOT-23** Package TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

## **Certified Quality**

For Reference Only

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# NE85633-T1B-R23-A Specifications

Manufacturer Part Number	NE85633-T1B-R23-A
Manufacturer	CEL
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	7GHz
Noise Figure (dB Typ @ f)	1.1dB @ 1GHz
Gain	11.5dB
Power - Max	200mW
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 20mA, 10V
Current - Collector (Ic) (Max)	100mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	SOT-23
	Report errors?

#### NE85633-T1B-R23-A Guarantees



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

## NE85633-T1B-R23-A Payment Methods



















# NE85633-T1B-R23-A Shipping Methods













If you have any question about NE85633-T1B-R23-A, please do not hesitate to contact us!

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